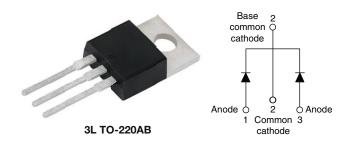
**Vishay Semiconductors** 

# High Performance Schottky Rectifier, 2 x 30 A



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PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 30 A					
V <sub>R</sub>	30 V					
V <sub>F</sub> at I <sub>F</sub>	0.44 V					
I <sub>RM</sub> max.	350 mA at 125 °C					
T <sub>J</sub> max.	150 °C					
E <sub>AS</sub>	13 mJ					
Package	3L TO-220AB					
Circuit configuration	Common cathode					

### **FEATURES**

- 150 °C T<sub>J</sub> operation
- · Low forward voltage drop



COMPLIANT

- High frequency operation HALOGEN • High purity, high temperature epoxy FREE encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	(MBOL CHARACTERISTICS					
I <sub>F(AV)</sub>	Rectangular waveform (per device)	60	А			
V <sub>RRM</sub>		30	V			
I <sub>FRM</sub>	T <sub>C</sub> = 120 °C (per leg)	60	А			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1500	A			
V <sub>F</sub>	30 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.44	V			
TJ	Range	-65 to +150	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-62CTQ030-M3	UNITS			
Maximum DC reverse voltage	V <sub>R</sub>	30	M			
Maximum working peak reverse voltage	V <sub>RWM</sub>	30	v			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS			
Maximum average forward per leg		50 % duty cycle at $T_{e} = 120$ °C	rectangular waveform	30			
current per device	I <sub>F(AV)</sub>	50 % duty cycle at $T_{C}$ = 120 °C, rectangular waveform		60	l		
Peak repetitive forward current per leg	I <sub>FRM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, $T_C = 127 \text{ °C}$		60	А		
Maximum peak one cycle non-repetitive	<b>1</b>	5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and with rated	1500			
surge current per leg	IFSM	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	300			
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 3 A, L = 2.9 mH		13	mJ		
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		3	А		

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ELECTR	DICAL C	DECIEIC	ATIONS
ELEVIE	NUCAL J	FEGIFIG	AIIVNJ

ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS			MAX.	UNITS		
		30 A	T <sub>.1</sub> = 25 °C	0.46	0.5			
Movimum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	60 A	1j=25 C	0.56	0.6	v		
Maximum forward voltage drop	VFM (17	30 A	T 105 %C	0.39	0.44	V		
		60 A	T <sub>J</sub> = 125 °C	0.54	0.59			
Maximum instantaneous reverse current		T <sub>J</sub> = 25 °C	Data d DO contra co	0.4	2.5			
Maximum instantaneous reverse current	I <sub>RM</sub>	T <sub>J</sub> = 125 °C	Rated DC voltage	180	350	mA		
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		30	00	pF		
Typical series inductance	L <sub>S</sub>	Measured from top of terminal to mounting plane			.0	nH		
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>			000	V/µs		

#### Note

Γ

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature rang	e T <sub>J</sub>	TJ		°C		
Maximum storage temperature range	e T <sub>Stg</sub>		-65 to +175	C		
Maximum thermal resistance, junction to case per leg	R <sub>thJC</sub>	DC operation	1.2	°C/W		
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	0,00		
Approvimeto weight			2	g		
Approximate weight			0.07	oz.		
	mum	Non-lubricated threads	6 (5)	kgf ⋅ cm		
Mounting torque maxi	mum	Non-Iubricateu tirreaus	12 (10)	(lbf · in)		
Marking device		Case style 3L TO-220AB	62CT	Q030		



# VS-62CTQ030-M3

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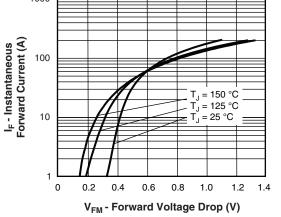


Fig. 1 - Maximum Forward Voltage Drop Characteristics

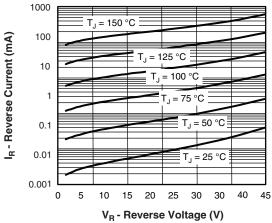


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

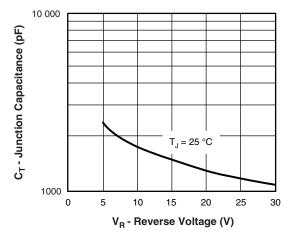


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

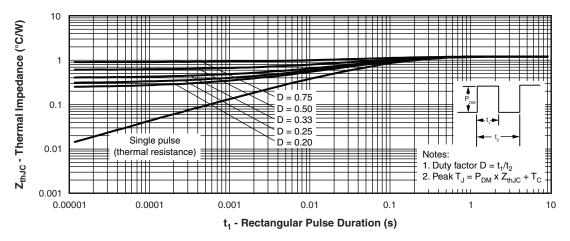
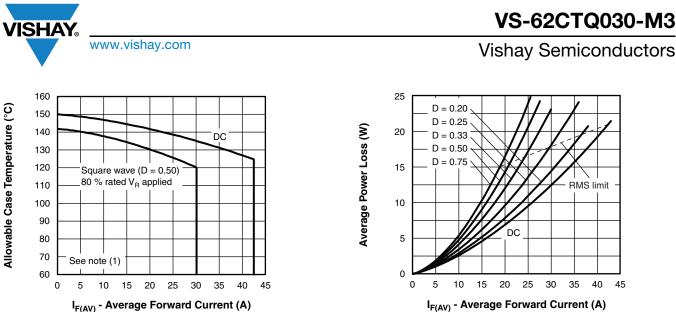


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

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I<sub>F(AV)</sub> - Average Forward Current (A)

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current



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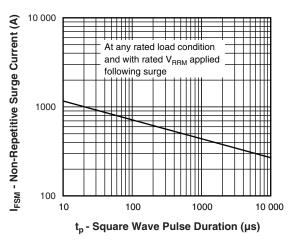


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

#### Note

 $^{(1)}$  Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC};$ Pd = forward power loss =  $I_{F(AV)} \times V_{FM}$  at ( $I_{F(AV)}/D$ ) (see fig. 6); Pd\_{REV} = inverse power loss =  $V_{R1} \times I_R (1 - D); I_R$  at  $V_{R1} = 80 \%$  rated  $V_R$ 



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### **ORDERING INFORMATION TABLE**

Device code	VS-	62	С	т	Q	030	-M3
	1	2	3	4	5	6	7
1	-	Vishay	Semico	onductor	s produ	ct	
2	-	Curren	t rating	(60 = 60	A)		
3	-	Circuit	configu	ration			
		C = Co	mmon o	cathode			
4	-	Packag	je				
		T = TC	-220				
5	-	Schottł	ky "Q" s	eries			
6	-	Voltage	e rating	(030 = 3	80 V)		
7	-	Enviro	nmental	digit			
		-M3 = ł	alogen	-free, Ro	oHS-con	npliant,	and ter

ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-62CTQ030-M3	50	1000	Antistatic plastic tube			

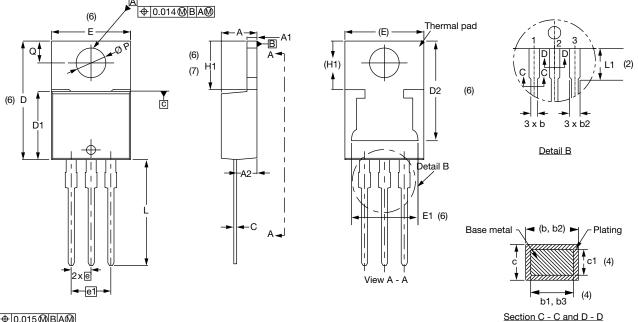
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96154				
Part marking information	www.vishay.com/doc?95028				
SPICE model	www.vishay.com/doc?95185				



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# **3L TO-220AB**

#### **DIMENSIONS** in millimeters and inches



⊕0.015@BA@



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

Conforms to JEDEC<sup>®</sup> outline TO-220AB

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	12.88	0.460	0.507	6
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Notes

 $^{(1)}\,$  Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(4)</sup> Dimension b1, b3, and c1 apply to base metal only

(5) Controlling dimensions: inches

<sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2, and E1

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> TO-220, except D2 (minimum)

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